

# 600W Halfbridge LLC Evaluation Board

EVAL 12V 600W LLC analog

EVAL 12V 600W LLC digital



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## ■ General Description

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# Example of System Understanding: Infineon Demo Solution for Titanium HV DC/DC stage

Half Bridge LLC with synchronous rectification in center tap configuration

$V_{in}$  350-410V<sub>DC</sub>

$V_{in\_nom}$  380V<sub>DC</sub>

$V_{out\_nom}$  12V<sub>DC</sub>

$I_{out}$  50A

$P_o$  600W

$f_{res}=f_0$  157kHz

$f_{min}$  90kHz

$f_{max}$  210kHz

Transformer turns ratio 16:1

$C_r$  66nF

$L_r$  15.5uH

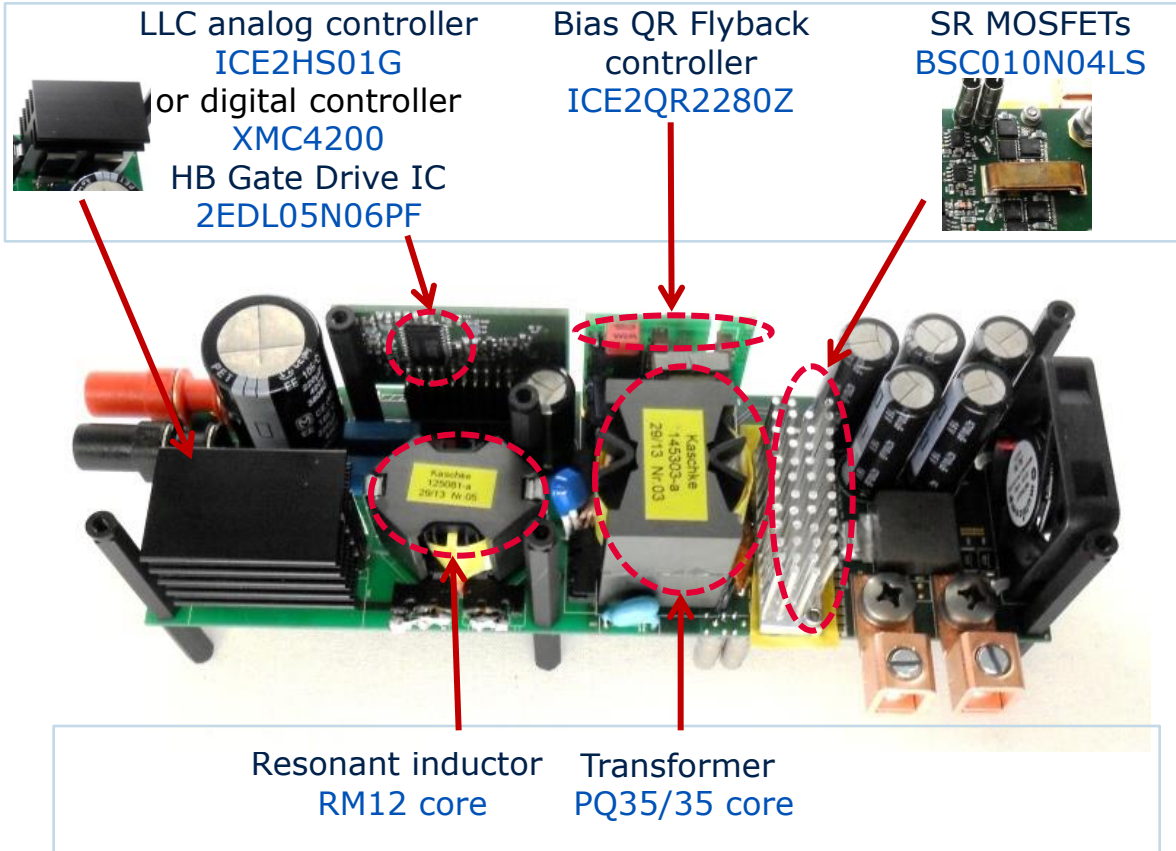
$L_m$  195uH

## Primary HV MOSFETs

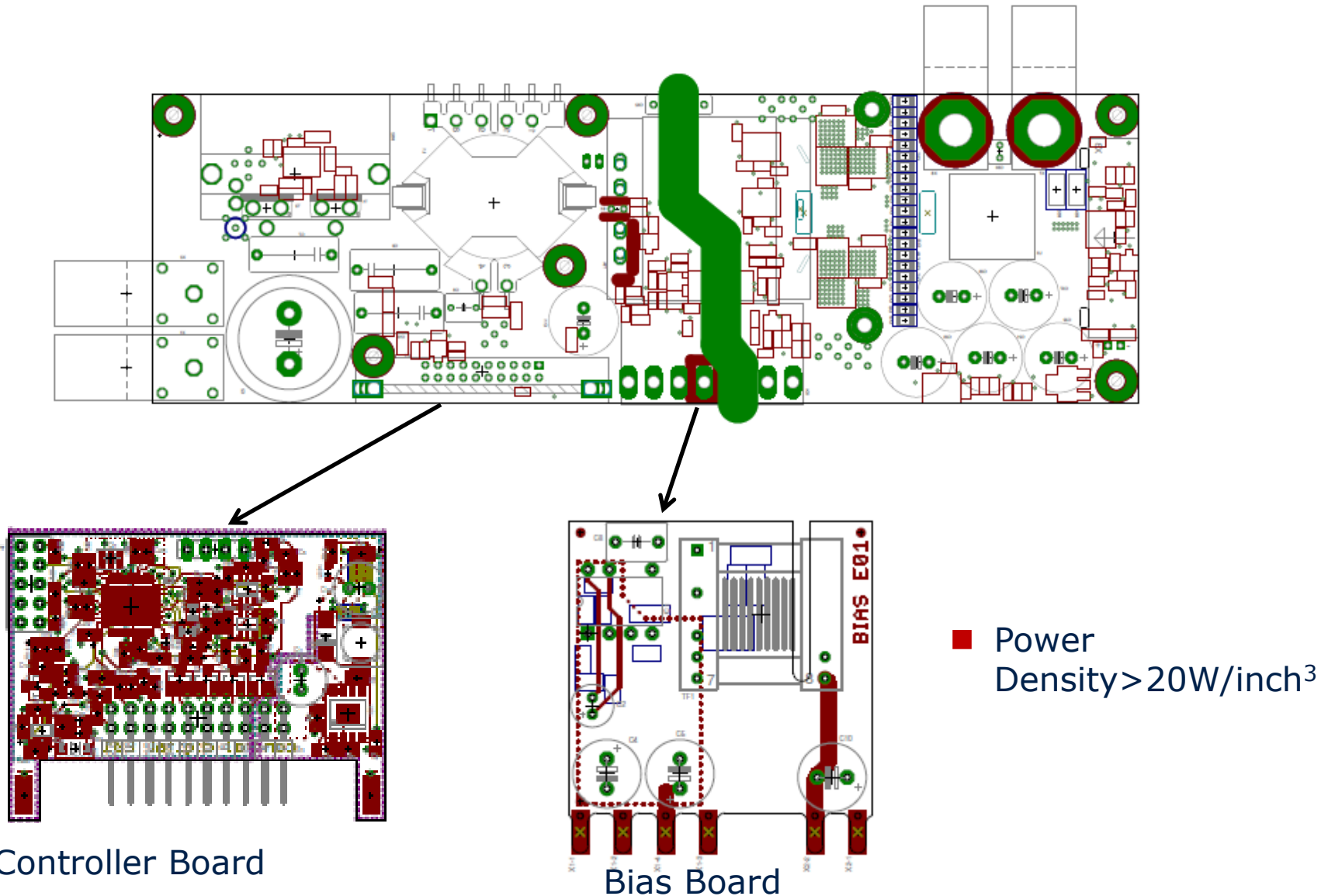
- **CoolMOS™ IPP60R190P6**
- Reduced Gate Charge ( $Q_g$ )
- Reduced  $E_{off}$
- High body diode ruggedness

## SR MOSFETs

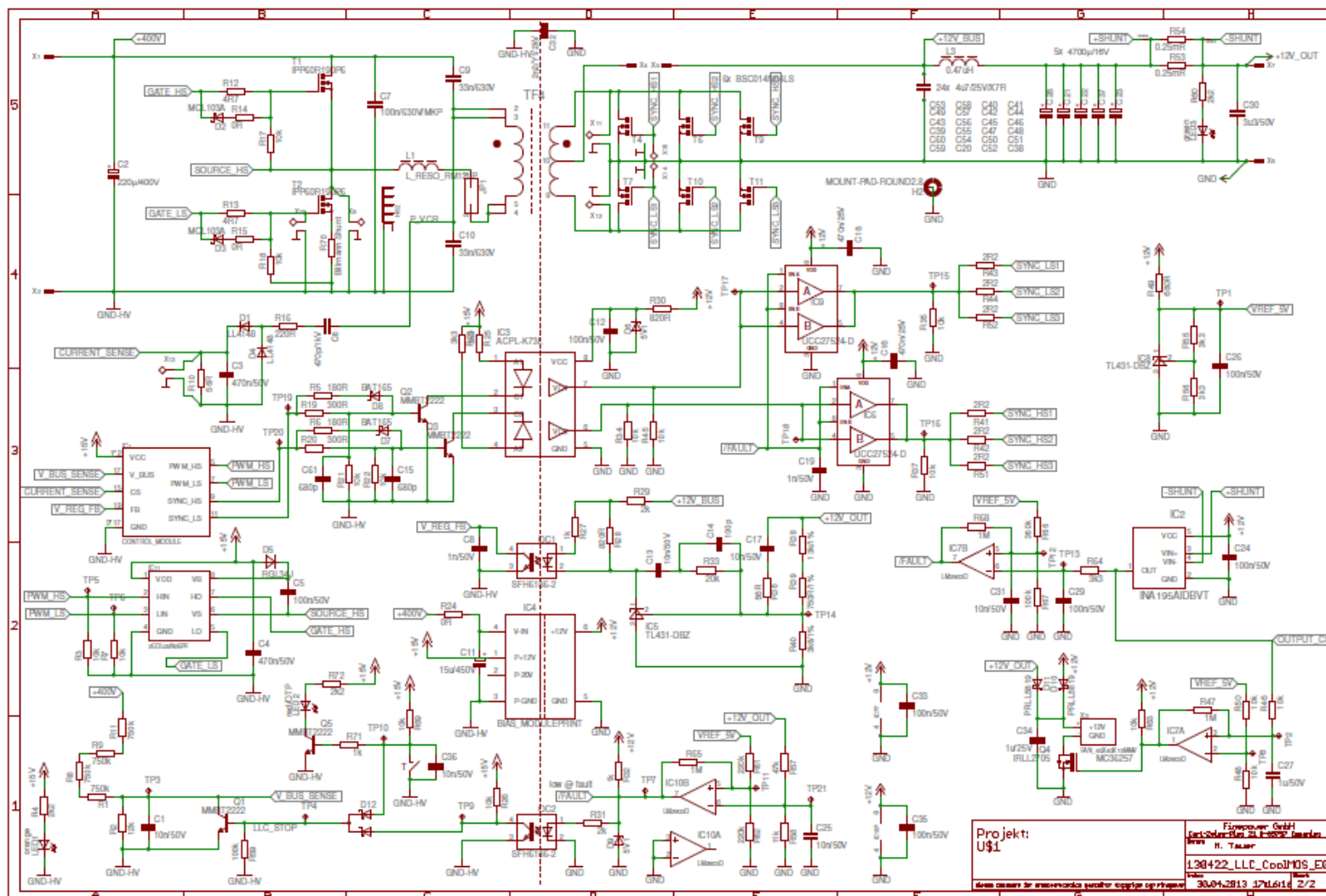
- **OptiMOS™ BSC010N04LS**
- New generation
- Best FOM  $R_{DS(on)} \times Q_g$
- Best FOM  $R_{DS(on)} \times Q_{oss}$



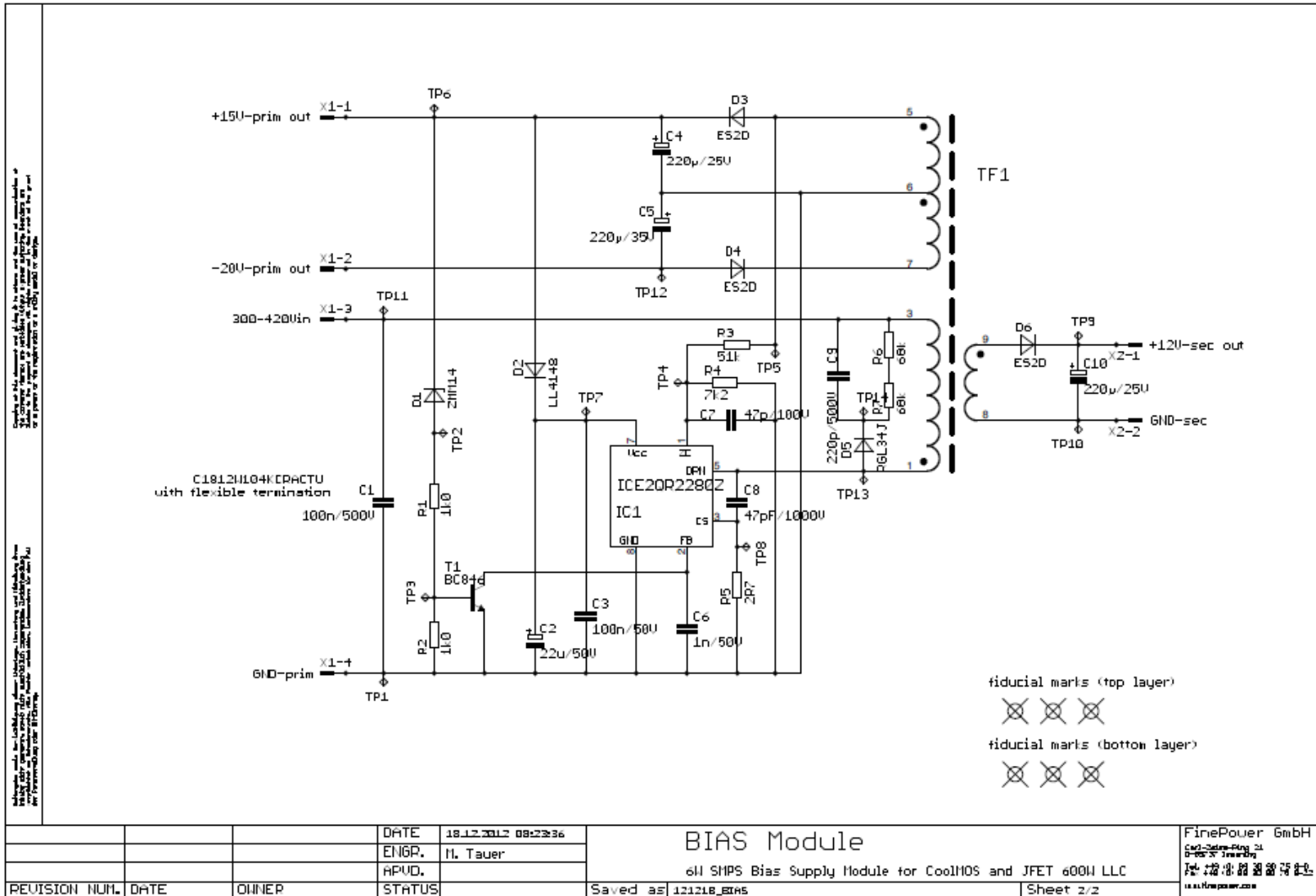
# PCB Boards Layout: Main Power Board and Control and Bias Daughter Boards



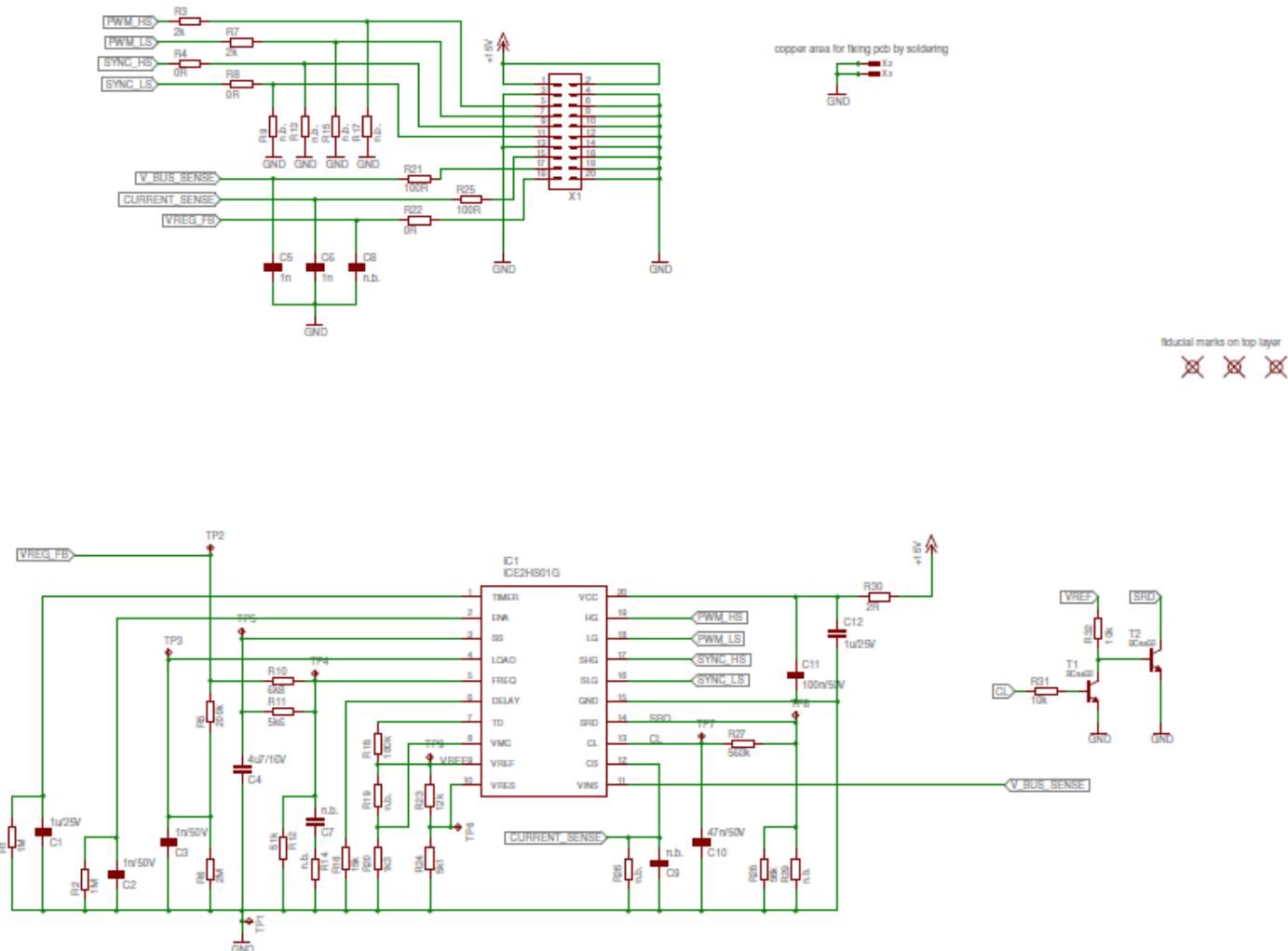
# Main Power Board Schematic



# Bias Board Schematic



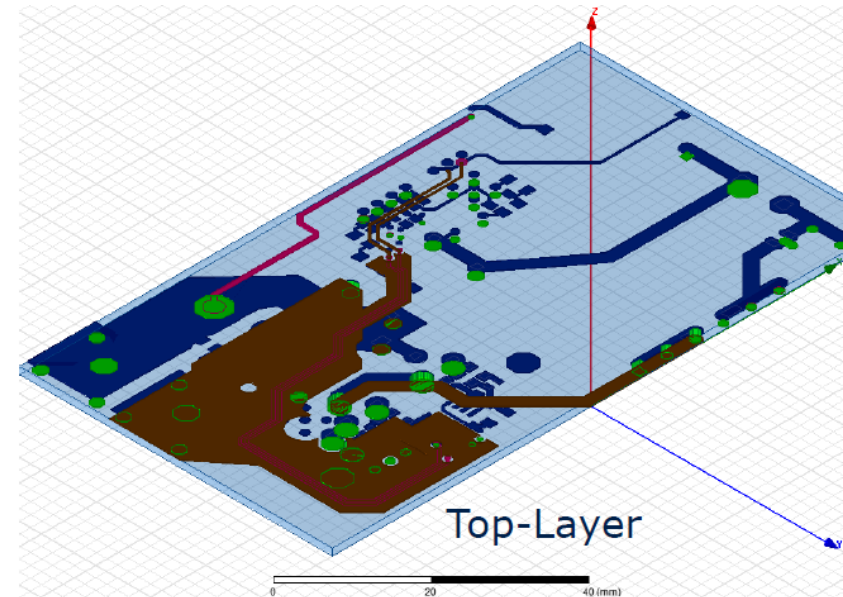
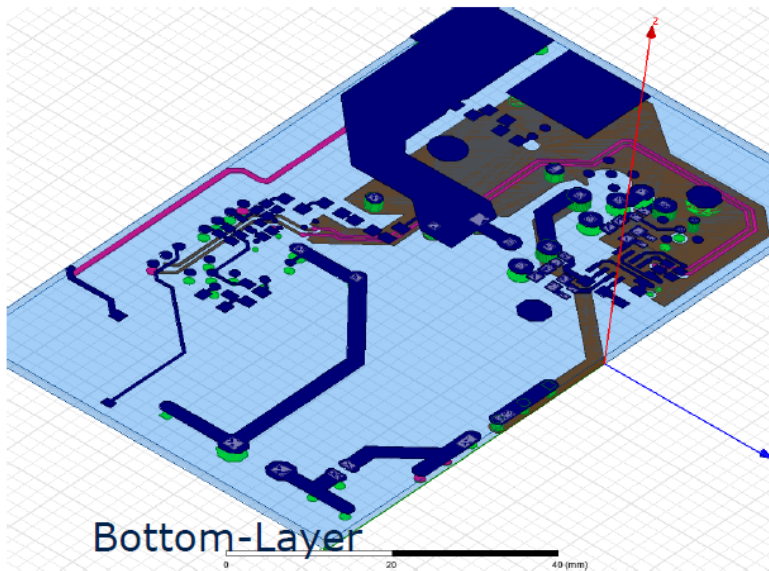
# Analog Control Board Schematic



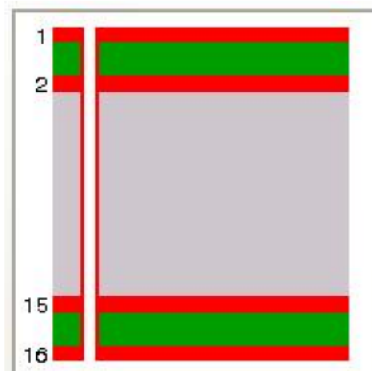




# PCB structure



## PCB-Stackup



Nr	Copper	Isolation
1	<input type="text" value="0.07mm"/>	<input type="text" value="0.15mm"/>
2	<input type="text" value="0.07mm"/>	<input type="text" value="0.93mm"/>
15	<input type="text" value="0.07mm"/>	<input type="text" value="0.15mm"/>
16	<input type="text" value="0.07mm"/>	
Gesamt: 1.51mm		

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■ General Description

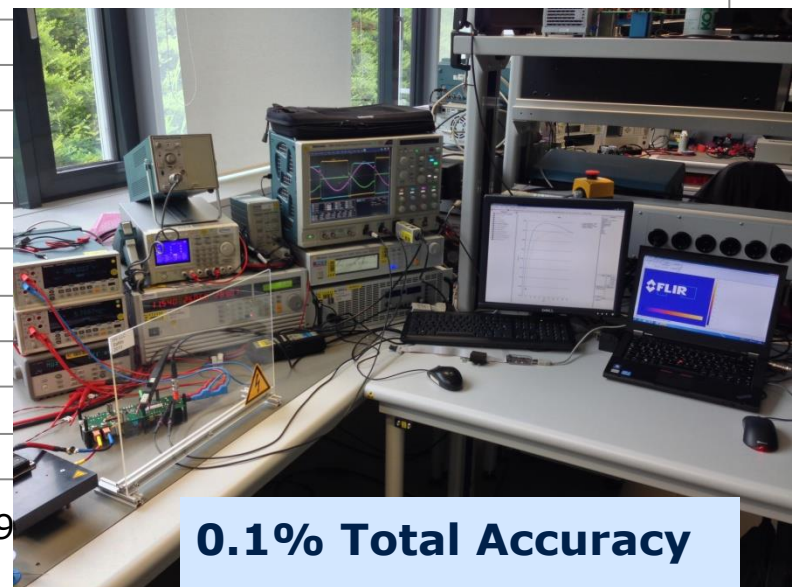
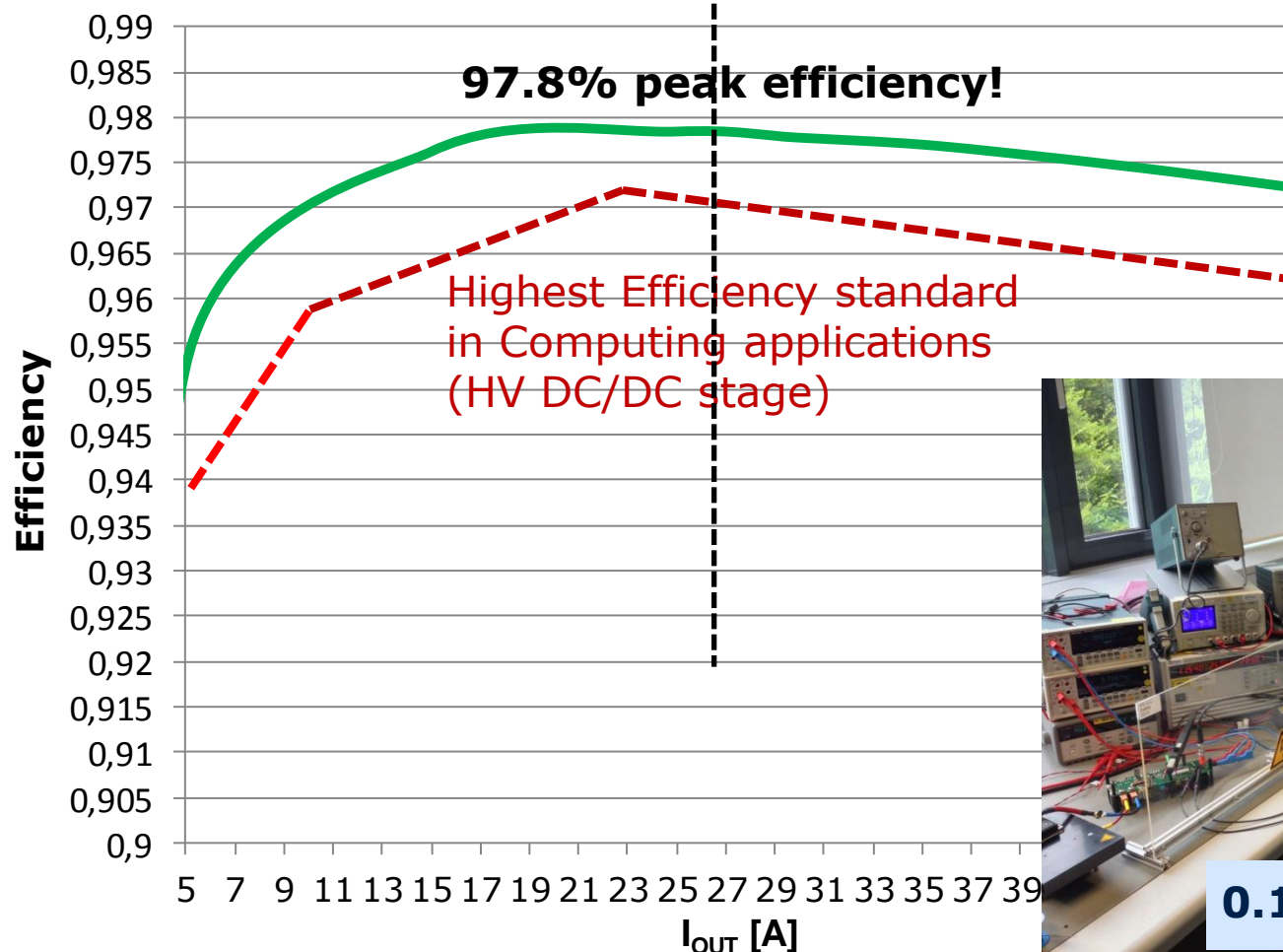
■ Efficiency Results

■ Design Concept

# Automated Efficiency Measurement

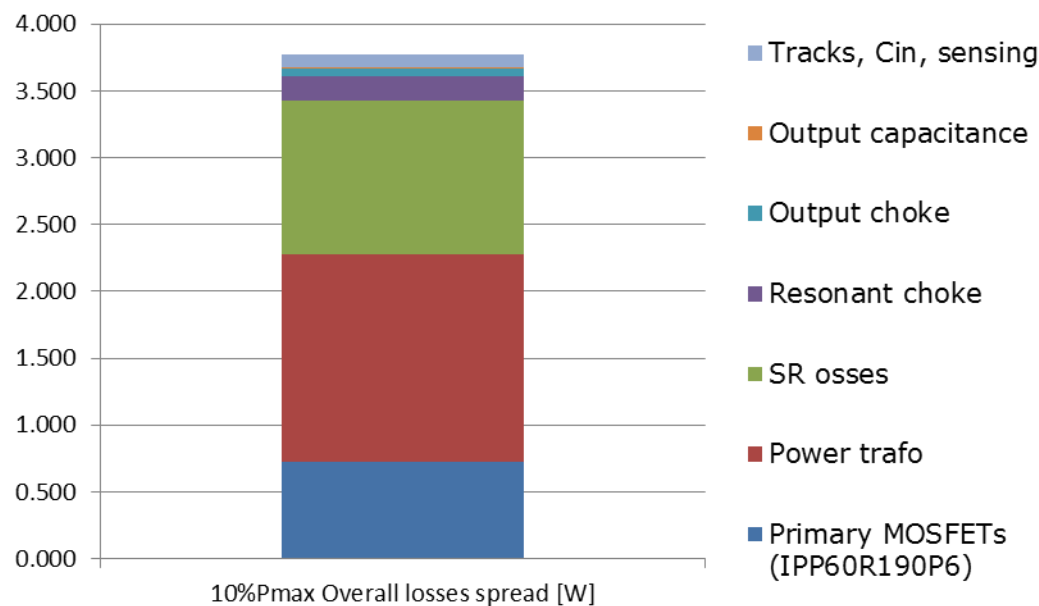
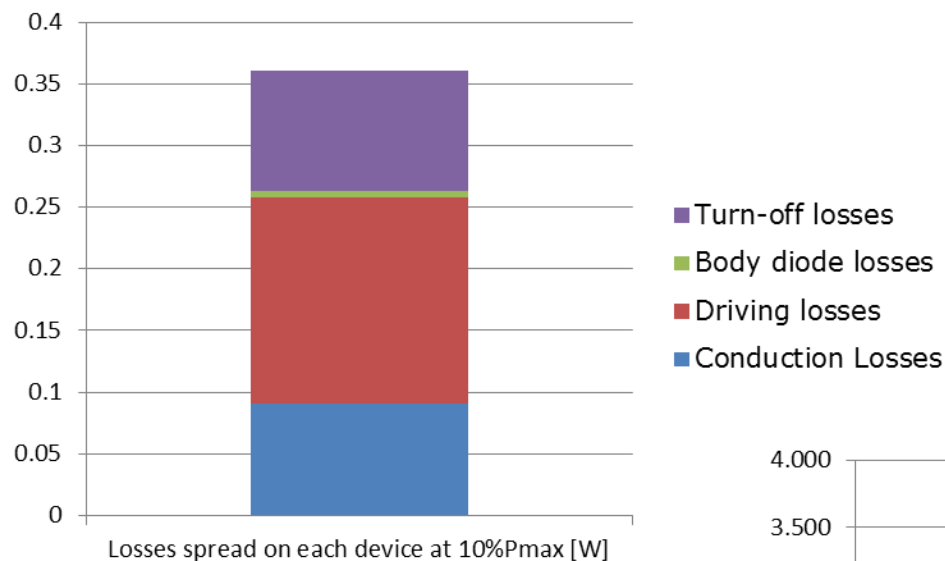
**Combination of converter design (resonant tank, transformer) and proper HV device selection**

**Proper selection of SR LV device and secondary side design**

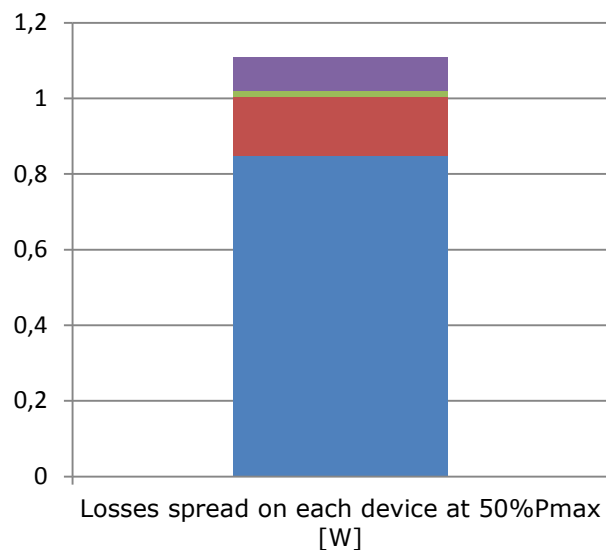


**0.1% Total Accuracy**

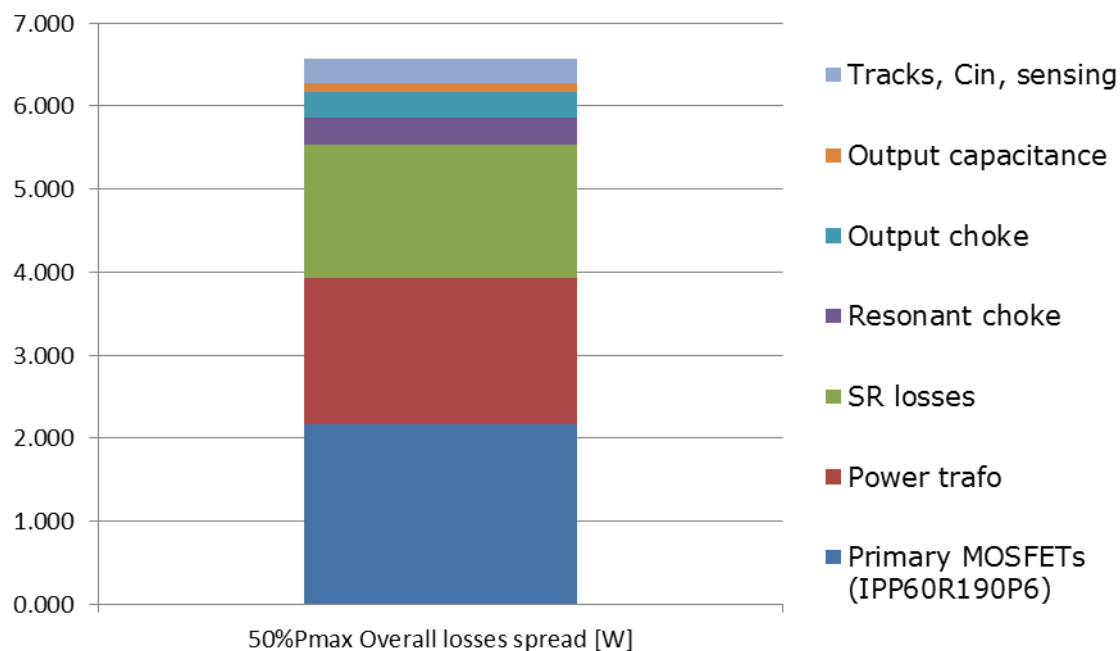
$10\%P_{\max} \quad V_{\text{in}} = 380V_{\text{dc}}$



$50\%P_{\max} \quad V_{\text{in}} = 380V_{\text{dc}}$

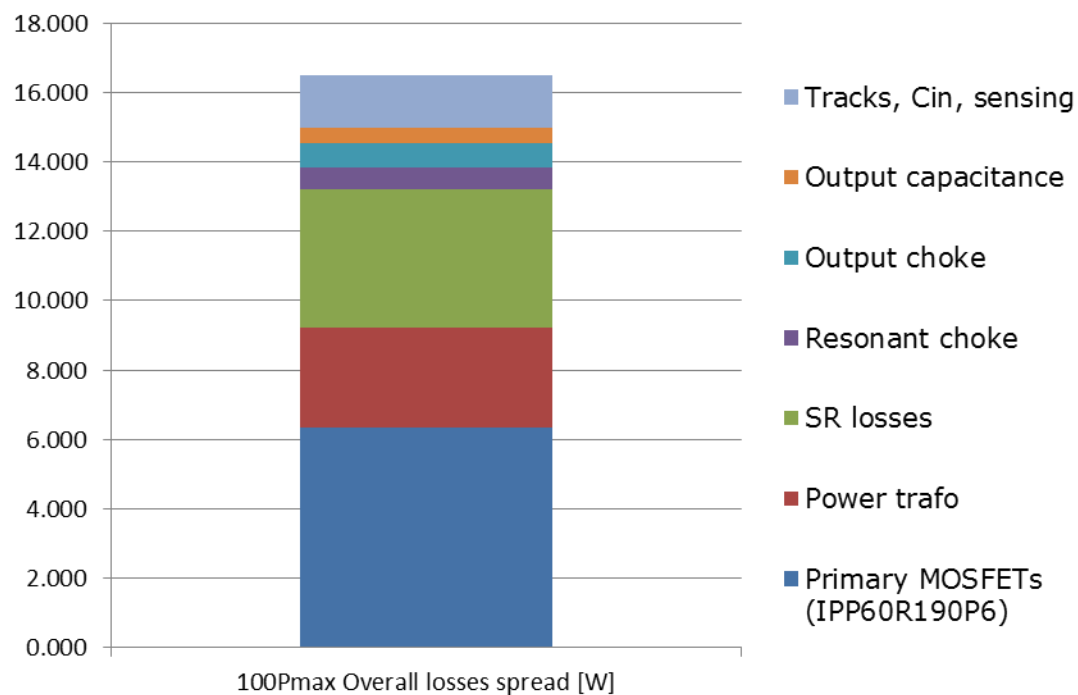
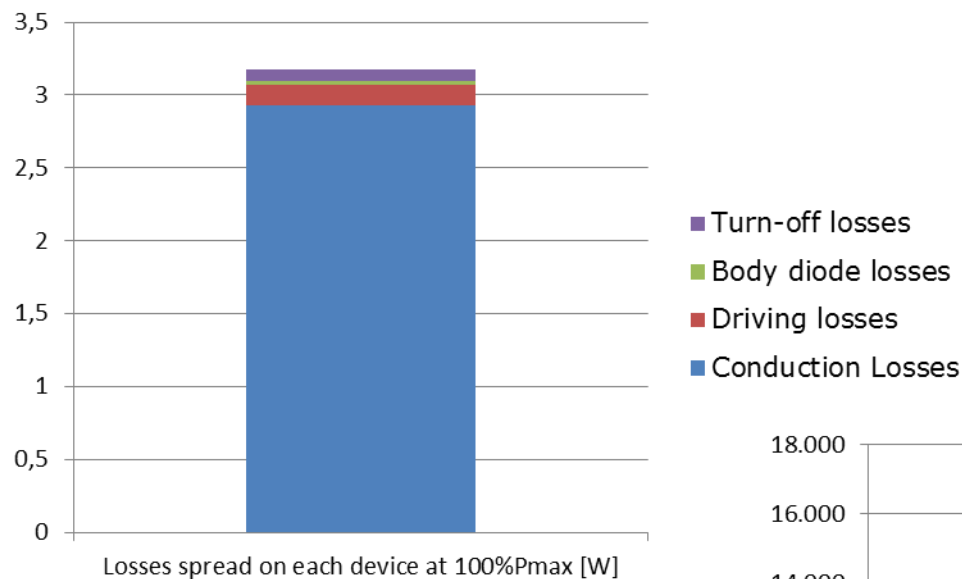


- Turn-off losses
- Body diode losses
- Driving losses
- Conduction Losses



- Tracks, Cin, sensing
- Output capacitance
- Output choke
- Resonant choke
- SR losses
- Power trafo
- Primary MOSFETs (IPP60R190P6)

$100\%P_{\max} \quad V_{\text{in}} = 380V_{\text{dc}}$



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# Design Procedure: Input Data

$$n = \frac{V_{in\_nom}}{2 \cdot V_{out\_nom}}$$

$$M_{min} \equiv K_{min}(Q, m, F_x) = \frac{n \cdot V_{o\_min}}{V_{in\_max} / 2}$$

$$M_{max} \equiv K_{max}(Q, m, F_x) = \frac{n \cdot V_{o\_max}}{V_{in\_min} / 2}$$

# Resonant Tank Components and Related Resonant Frequencies

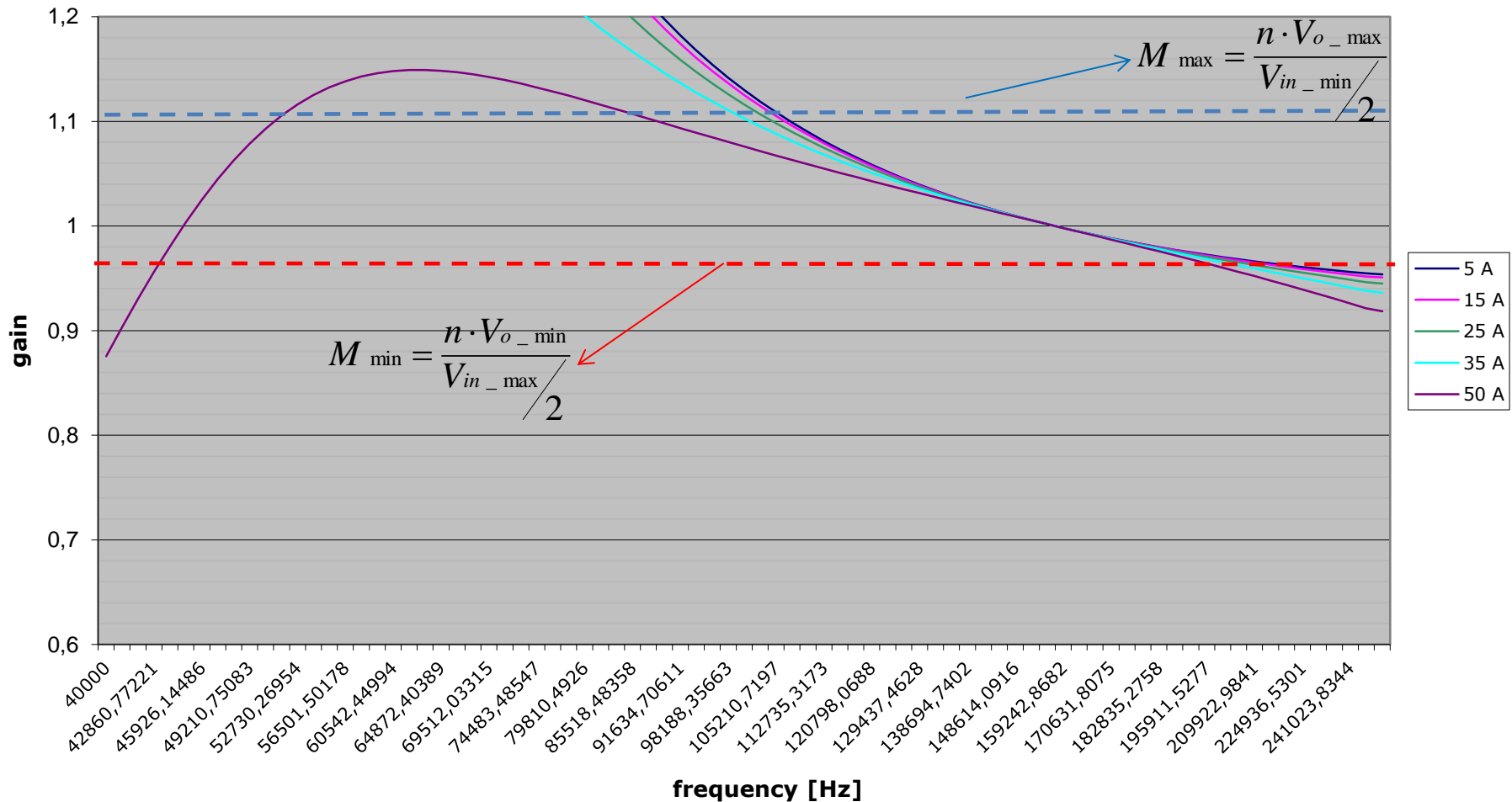
- $n = V_{in\_nom} / (2 \times V_o) = 380 / (2 \times 12) \approx 16$
- $L_m = 195 \mu H$
- $L_r = 15.5 \mu H$
- $L_n = L_m / L_r = 12.5$
- $C_r = 66 nF$

$$f_o = \frac{1}{2\pi \cdot \sqrt{L_r \cdot C_r}} = 157 kHz$$

$$f_p = \frac{1}{2\pi \cdot \sqrt{(L_r + L_m) \cdot C_r}} = 42.7 kHz$$

# Gain Curves

**dc-gain curve (600W LLC hardware revision E02)**



# Energy Related Calculations (Ref. IPP60R190P6 Device Parameters)

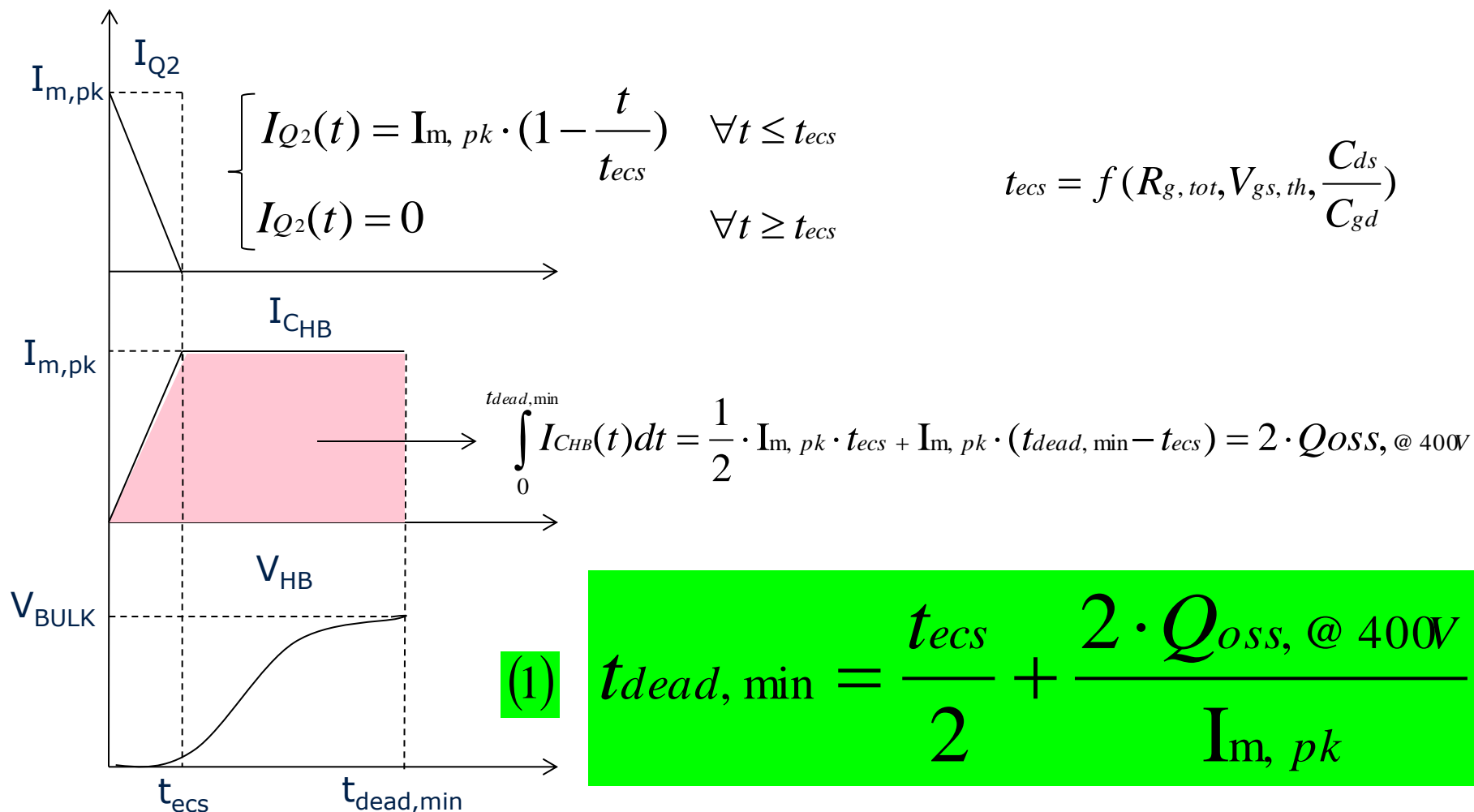
$$I_{mag\_min} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw\_max} \cdot L_m} = 0.672 A$$

$$En_{res\_min} = \frac{1}{2} \cdot (L_m + L_r) \cdot I_{mag\_min}^2 = 95.1 \mu J$$

$$En_{cap\_max} = \frac{1}{2} \cdot (2Co(er)) \cdot V_{DS\_max}^2 \approx 9 \mu J$$

$$\Rightarrow En_{res\_min} > En_{cap\_max}$$

# $Q_{oss}, I_{mag,pk}, t_{dead,min}, t_{ecs}$ Relationship



# Time Related Calculations

## (Ref. IPP60R190P6 Device Parameters)

$$I_{mag\_min} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw\_max} \cdot L_m} = 0.672A$$

$$I_{mag\_max} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw\_min} \cdot L_m} = 1.66A$$

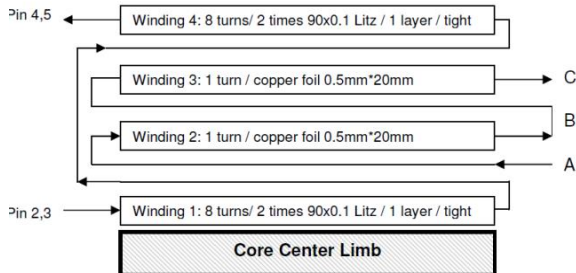
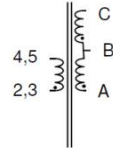
$$t_{dead, min} = \frac{t_{ecs}}{2} + \frac{2 \cdot Q_{oss, @ 400V}}{I_{mag, max}} \approx 130n sec$$

$$t_{dead, max} = \frac{t_{ecs}}{2} + \frac{2 \cdot Q_{oss, @ 400V}}{I_{mag, min}} \approx 311n sec$$

# Main Transformer Structure: PQ35/35 Core with TDK PC95 Ferrite Material

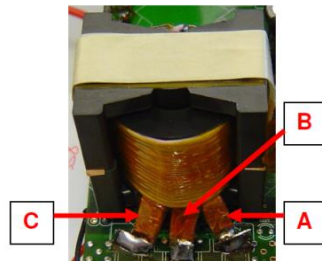
## LLC main transformer

Core form and material	PQ35/35, PC95 (TDK)
Bobbin	Epcos, B65882E0012T001
Primary inductance $L_p$	195 $\mu$ H, measured between 2,3 and 4,5, other pins open
Leakage inductance $L_k$	1,5 $\mu$ H, measured between 2,3 and 4,5, other pins shorted
Isolation voltage $V_{iso}$	2500V <sub>rms</sub> / 50Hz, 1min (between 2,3,4,5 and A,B,C)



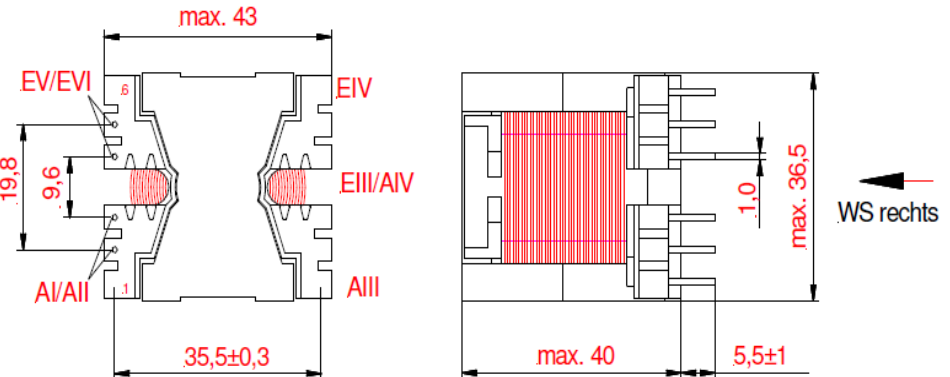
Windings	Start	End	Wire	Turns	Layers	Method
1	2,3	Float	2 times 90x0.1mm Litz	8	1	Tight
2	A	B	0.5mm*20mm copper foil	1	1	Tight
3	B	C	0.5mm*20mm copper foil	1	1	Tight
4	Float	4,5	2 times 90x0.1mm Litz	8	1	Tigh

Connection of secondary copper foil:

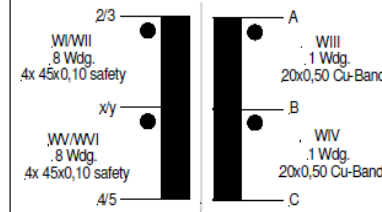


## Technical Data Sheet

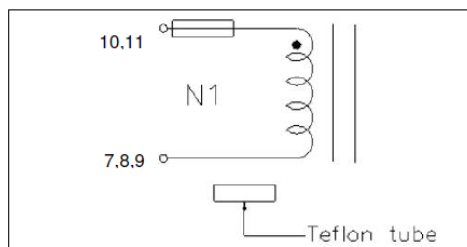
Customer : <b>Infineon Technologies</b>	Part designation : <b>SP-PQ 35/35</b>	Customer part number :
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Core / material / air gap	PQ35/35 / K2008 or equiv. / 0,25
Nominal inductance	LI+LVI = 195 $\mu$ H $\pm$ 15%
Ratio of transformation	8 : 1 : 1 : 8
Dielectric strength (50Hz/1s)	2,5kV (prim - sec)
Leakage inductance	max. 3 $\mu$ H
Operating temperature	-25°C - +125°C
Storage temperature	-25°C - +85°C
Humidity- / application class	F (DIN 40040)



Core form and material	RM12, N87 (Epcos)
Bobbin	Epcos, B65816C1512T001
Inductance L	14uH



Windings	Start	End	Wire	Turns	Layers	Method
N1	7.8.9	10.11	120x0.1mm Litz	9	1	Tight

**Technical Data Sheet**

Customer : <b>Infineon Technologies</b>	Part designation : <b>SP-RM 12</b>	Customer part number :
--	---------------------------------------	------------------------

Core / material / air gap: RM12 / K2008 or equiv. / 1,1

Nominal inductance:  $L = 14\mu H \pm 15\%$

Operating temperature: -25°C - +125°C

Storage temperature: -25°C - +85°C

Humidity- / application class: F (DIN 40040)



# Support Slides 600W LLC Evaluation Board



## Evaluation Board Page

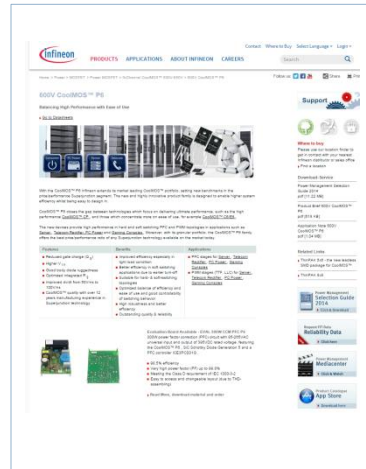
- Technical Description
- Datasheets
- Parameters
- Related material
- Videos



- [www.infineon.com/600w-llc-evaluationboard-a](http://www.infineon.com/600w-llc-evaluationboard-a)
- [www.infineon.com/600w-llc-evaluationboard-d](http://www.infineon.com/600w-llc-evaluationboard-d)

## Product Family Pages

- Product Brief
- Application Notes
- Selection Guides
- Datasheets and Portfolio
- Videos
- Simulation Models



- [www.infineon.com/p6](http://www.infineon.com/p6)
- [www.infineon.com/xmc](http://www.infineon.com/xmc)
- [Resonant Mode Controller](http://www.infineon.com/Resonant Mode Controller)
- [www.infineon.com/optimos5-40v60v](http://www.infineon.com/optimos5-40v60v)

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